

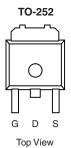
WSF28N06-VB Datasheet N-Channel 6 0-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$r_{DS(on)}$ (Ω)	I _D (A) ^a		
60	0.026 at V _{GS} = 10 V	45		
	0.029 at V _{GS} = 4.5 V	40		

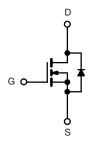
FEATURES

- Trench Power MOSFET
- 175 °C Junction Temperature





Drain Connected to Tab



N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_C = 3$	25 °C, unless othe	rwise noted			
Parameter		Symbol	Limit	Unit	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current (T _J = 175 °C) ^b	T _C = 25 °C	L-	40		
	T _C = 100 °C	l _D	35		
Pulsed Drain Current		I _{DM}	100	А	
Continuous Source Current (Diode Conduction)		I _S	23		
Avalanche Current		I _{AS}	20	1	
Single Avalanche Energy (Duty Cycle ≤ 1 %)	L = 0.1 mH	E _{AS}	20	mJ	
Maximum Daylar Dissination	T _C = 25 °C	D.	100	14/	
Maximum Power Dissipation	T _A = 25 °C	P _D –	3 ^a	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 10 sec	R _{thJA}	18	22	°C/W
waximum Junction-to-Ambient	Steady State		40	50	
Maximum Junction-to-Case		R _{thJC}	3.2	4	

Notes:

a. Surface Mounted on 1" x 1" FR4 board, $t \le 10$ sec.



SPECIFICATIONS $T_J = 25$ °C, unless otherwise noted Parameter Symbol Test Conditions Min Typa Max Unit								
Symbol	Test Conditions	Min	Typ ^a	Max	Unit			
			1					
	40 / D 1	60			V			
V _{GS(th)}		1.0	2.0	3.0	Ů			
I _{GSS}	20 00			± 100	nA			
	50 00			1				
I _{DSS}				50	μΑ			
	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			250				
I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	50			Α			
	V _{GS} = 10 V, I _D = 15 A		0.026					
r	V _{GS} = 10 V, I _D = 15 A, T _J = 125 °C	125 °C 0.055						
DS(on)	V _{GS} = 10 V, I _D = 15 A, T _J = 175 °C		0.069		Ω			
	V _{GS} = 4.5 V, I _D = 10 A		0.029					
9 _{fs}	V _{DS} = 15 V, I _D = 15 A		20		S			
C _{iss}			1850		pF			
C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 25 \text{ V}, f = 1 \text{ MHz}$		140					
C _{rss}			60					
Q_g			11	17	nC			
Q _{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 23 \text{ A}$		3					
Q_{gd}			3					
t _{d(on)}			8	15				
t _r	$V_{DD} = 30 \text{ V, R}_{L} = 1.3 \Omega$		15	25	ns			
t _{d(off)}	$I_D \cong 23 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 2.5 \Omega$		30	45				
t _f			25	40				
racteristics	(T _C = 25 °C)			l				
I _{SM}				50	Α			
V_{SD}	I _F = 15 A, V _{GS} = 0 V		1.0	1.5	V			
t _{rr}	I _F = 15 A, di/dt = 100 A/μs		30	60	ns			
	I_{DSS} $I_{D(on)}$ $I_{D(on)}$ g_{fs} C_{iss} C_{oss} C_{rss} Q_{g} Q_{gs} Q_{gd} $t_{d(on)}$ t_{r} $t_{d(off)}$ t_{f} $aracteristics$ I_{SM} V_{SD}	$\begin{array}{ c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 10 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 15 \text{ A} \\ \hline \hline C_{iss} & V_{GS} = 0 \text{ V, } V_{DS} = 25 \text{ V, } f = 1 \text{ MHz} \\ \hline \hline C_{rss} & V_{GS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline \hline Q_{g} & V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline Q_{gd} & t_{d(on)} & t_r & V_{DD} = 30 \text{ V, } R_L = 1.3 \Omega \\ \hline I_D \cong 23 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 2.5 \Omega \\ \hline \\ \textbf{I}_{SM} & V_{SD} & I_F = 15 \text{ A, } V_{GS} = 0 \text{ V} \\ \hline \end{array}$	$\begin{array}{ c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} & 1.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 125 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 10 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 15 \text{ A} \\ \hline \hline C_{ISS} \\ \hline C_{OSS} \\ \hline C_{SS} \\ \hline C_{QS} \\ \hline Q_{QS} \\ \hline Q_{QS} \\ \hline V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} \\ \hline Q_{Qd} \\ \hline t_{d(on)} \\ \hline t_r \\ \hline t_{d(off)} \\ \hline t_f \\ \hline \text{aracteristics} \\ \hline (T_C = 25 \text{ °C}) \\ \hline I_{SM} \\ \hline V_{SD} \\ \hline \end{array}$	$\begin{array}{ c c c c }\hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = 250 \mu\text{A} & 1.0 & 2.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 175 \text{ °C} \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 10 \text{ A} \\ \hline V_{DS} = 15 \text{ V, } I_D = 15 \text{ A} \\ \hline C_{rss} \\ \hline C_{rss} \\ \hline C_{Oss} \\ \hline C_{gs} \\$	$\begin{array}{ c c c c c }\hline V_{(BR)DSS} & V_{GS} = 0 \text{ V, } I_D = 250 \mu\text{A} & 60 & \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = 250 \mu\text{A} & 1.0 & 2.0 & 3.0 \\ \hline I_{GSS} & V_{DS} = 0 \text{ V, } V_{GS} = \pm 20 \text{ V} & \pm 100 \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} & 1 & \\ \hline I_{DSS} & V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V} & 1 & \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} & 50 \\ \hline V_{DS} = 60 \text{ V, } V_{GS} = 0 \text{ V, } T_J = 125 \text{ °C} & 250 \\ \hline I_{D(on)} & V_{DS} = 5 \text{ V, } V_{GS} = 10 \text{ V} & 50 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} & 0.026 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A} & 0.026 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 125 \text{ °C} & 0.069 & \\ \hline V_{GS} = 10 \text{ V, } I_D = 15 \text{ A}, T_J = 175 \text{ °C} & 0.069 & \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 10 \text{ A} & 0.029 & \\ \hline V_{GS} = 4.5 \text{ V, } I_D = 15 \text{ A} & 20 & \\ \hline \hline \\ \hline C_{ISS} & V_{GS} = 0 \text{ V, } V_{DS} = 25 \text{ V, } f = 1 \text{ MHz} & 140 & \\ \hline \hline C_{TSS} & 60 & \\ \hline Q_g & 11 & 17 & \\ \hline Q_{gS} & V_{DS} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} & 3 & \\ \hline Q_{gd} & 3 & 11 & 17 & \\ \hline V_{DD} = 30 \text{ V, } V_{GS} = 10 \text{ V, } I_D = 23 \text{ A} & 3 & \\ \hline I_D \cong 23 \text{ A, } V_{GEN} = 10 \text{ V, } R_g = 2.5 \Omega & 30 & 45 & \\ \hline I_f & 25 \text{ 40} & \\ \hline \\ \text{aracteristics} & (T_C = 25 \text{ °C}) & \\ \hline \\ \hline \\ \hline \\ \hline \end{array}$			

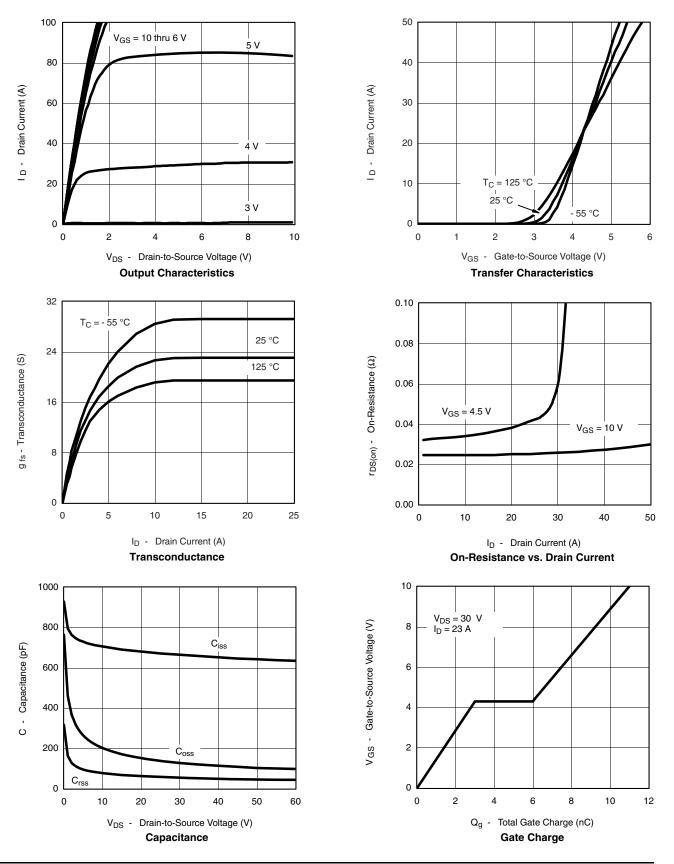
Notes:

- a. For design aid only; not subject to production testing.
- b. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

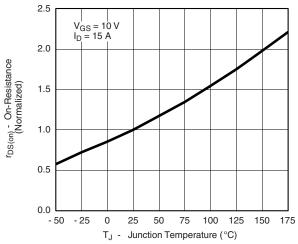


TYPICAL CHARACTERISTICS 25 °C unless noted

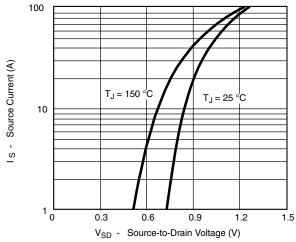




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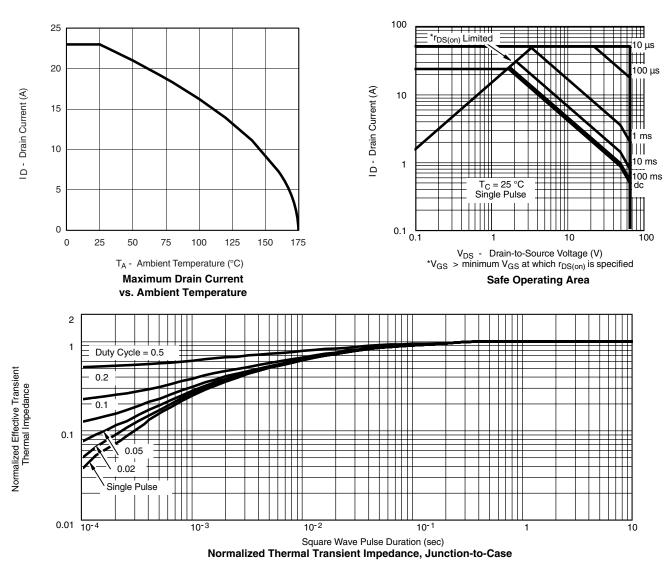
On-Resistance vs. Junction Temperature



Source-Drain Diode Forward Voltage



THERMAL RATINGS





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